

Observation of quantum vortex tunneling  
in a 2D superconductor at low T

or

Vortex variable range hopping in  
 $\text{YBa}_2\text{Cu}_3\text{O}_{7-\delta}$  thin films

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In collaboration with A. Auerbach and E. Polturak

*Motivation: to look for*  
**Tunneling magnetoresistance in a 2D  
superconductor**

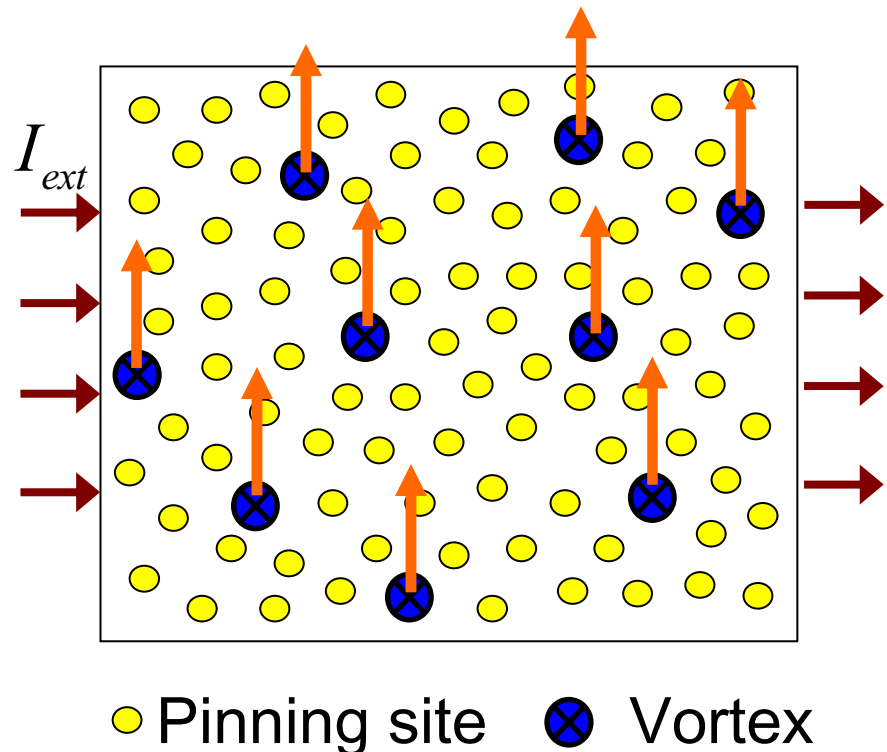
Flux flow resistance ( $R_{ff}$ ) and magneto-resistance (MR) develop when an external current leads to the motion of vortices. Then:

$$\Rightarrow V_{induced} = -\frac{d\phi}{dt}$$

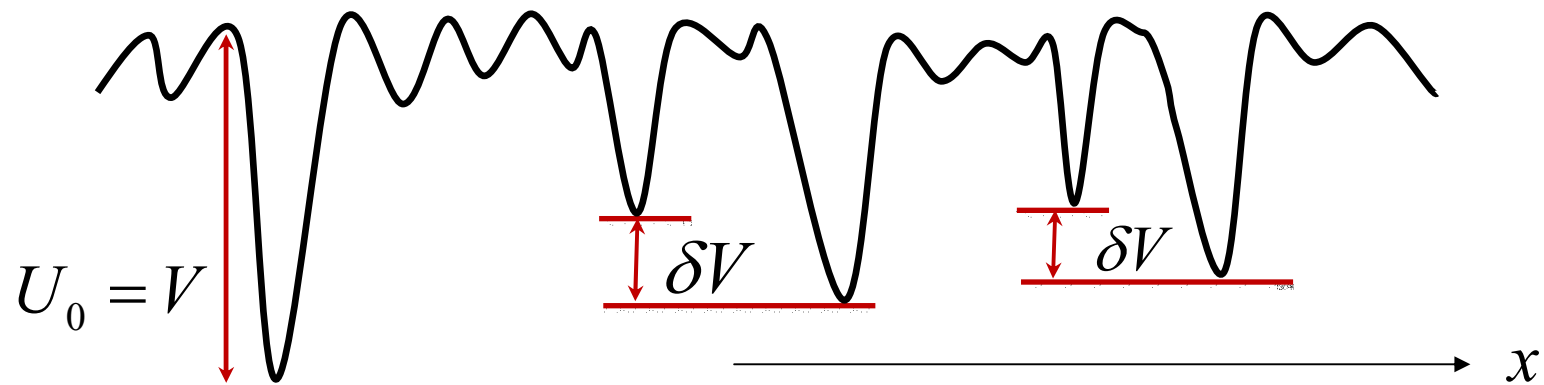
This yields

$$R_{ff} = \frac{V_{induced}}{I}$$

Note that  $MR \equiv R(H) - R(0)$



The pinning landscape in a superconductor:



Specifically, one can distinguish between two regimes

1. At high temperatures the pinning energy  $U_0$  is much weaker than **thermal activation**  $\Rightarrow$  flux flow or flux creep

$$R_{ff} \propto \exp\left(-\frac{U_0}{k_B T}\right)$$

2. At low temperatures the pinning energy  $U_0$  is much stronger than thermal activation  $\Rightarrow$  vortex motion via **quantum tunneling**

A . Auerbach, D. P. Arovas and S. Ghosh

[Phys. Rev. B **74**, 064511 (2006)], had found tunneling MR

$$\rho = \left( \frac{h}{2e} \right)^2 \gamma_0 [n_v(B)] e^{\left( -\frac{T_0}{T} \right)^{\frac{1}{3}}}$$

where  $\gamma_0$  is the vortex conductivity,  $n_v$  is the vortex density and  $T_0$  is given by:

$$T_0(\text{film}) = K \delta \bar{V} \left( \frac{\pi n_s}{n_{pin} N_{layers}} \right)^2$$

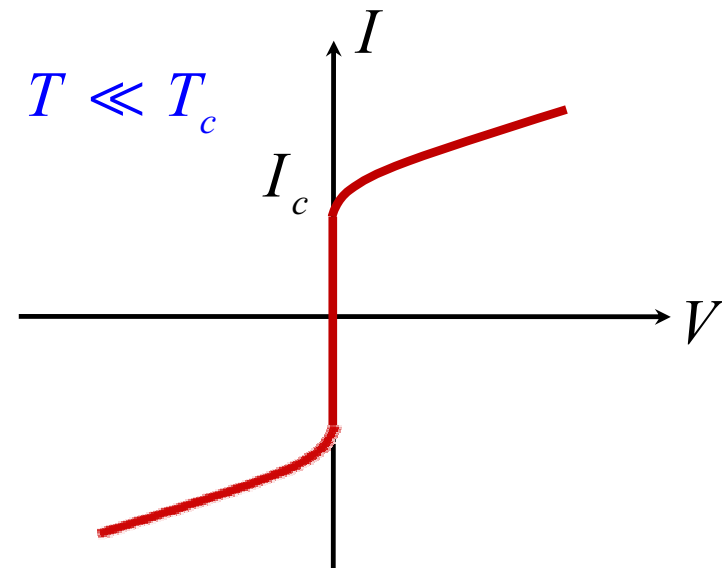
Where  $K \sim 1$ ,  $\delta \bar{V}$  is the average pinning energy variation,  $n_s$  is the pairs density,  $n_{pin}$  is the pinning sites density and  $N_{layers}$  is the number of  $\text{CuO}_2$  planes in the film

- The 1/3 exponent indicates VRH in 2D
- For 3D VRH this power would be 1/4

In order to test Auerbach, Arovas and Gosh prediction we used a 1m long YBCO Meander line

## Why should one use a long meander line?

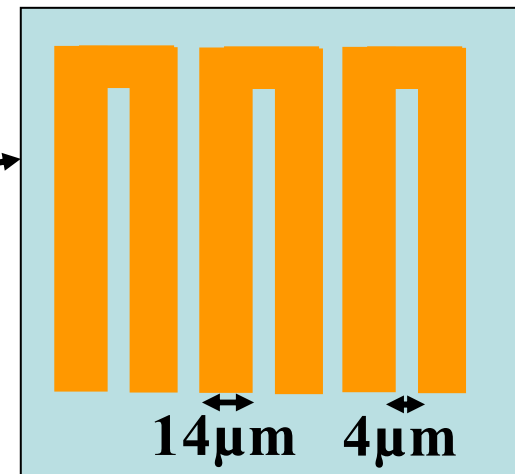
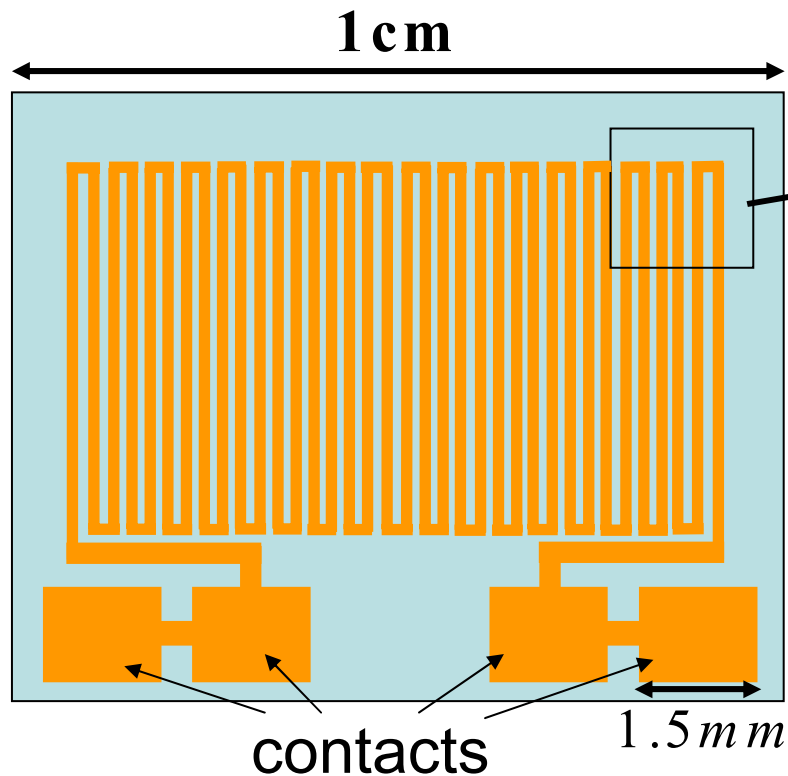
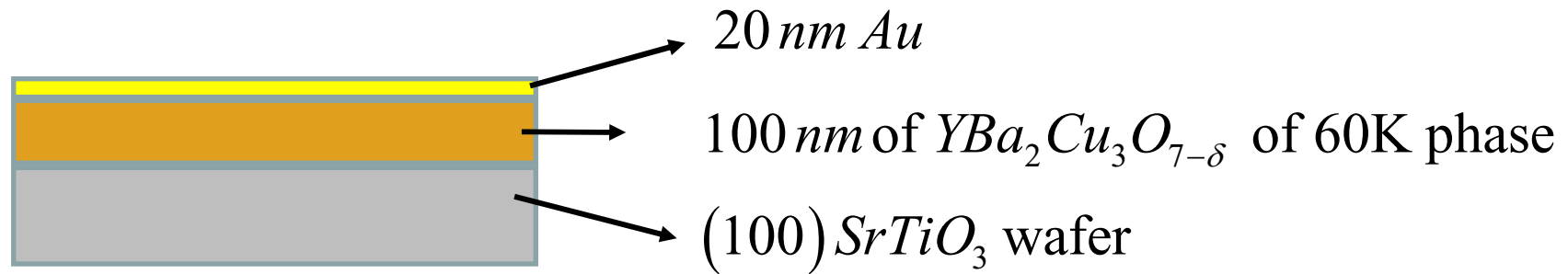
In a short microbridge under magnetic field of several Tesla, the induced voltage is very small and critical current develops already at about 10-20 K below  $T_c$ .



⇒ The  $R_{ff}$  resistance can't be measured at low T

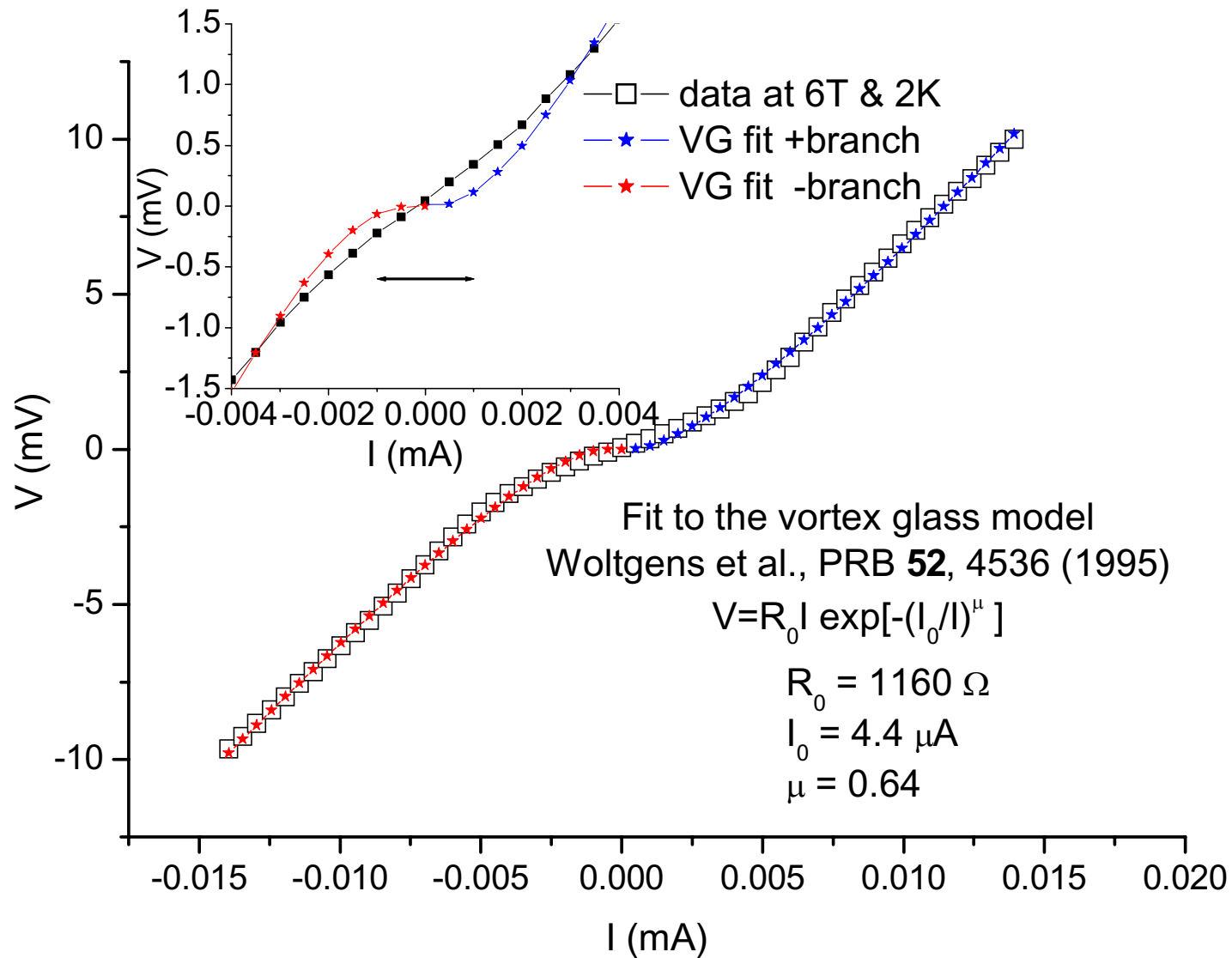
In contrast, in a long meander line the induced voltage is large, and the resistance can be measured down to very low T.

# The meanderline sample



A 1 m long YBCO  
Meander line

# Comparison to the vortex glass model

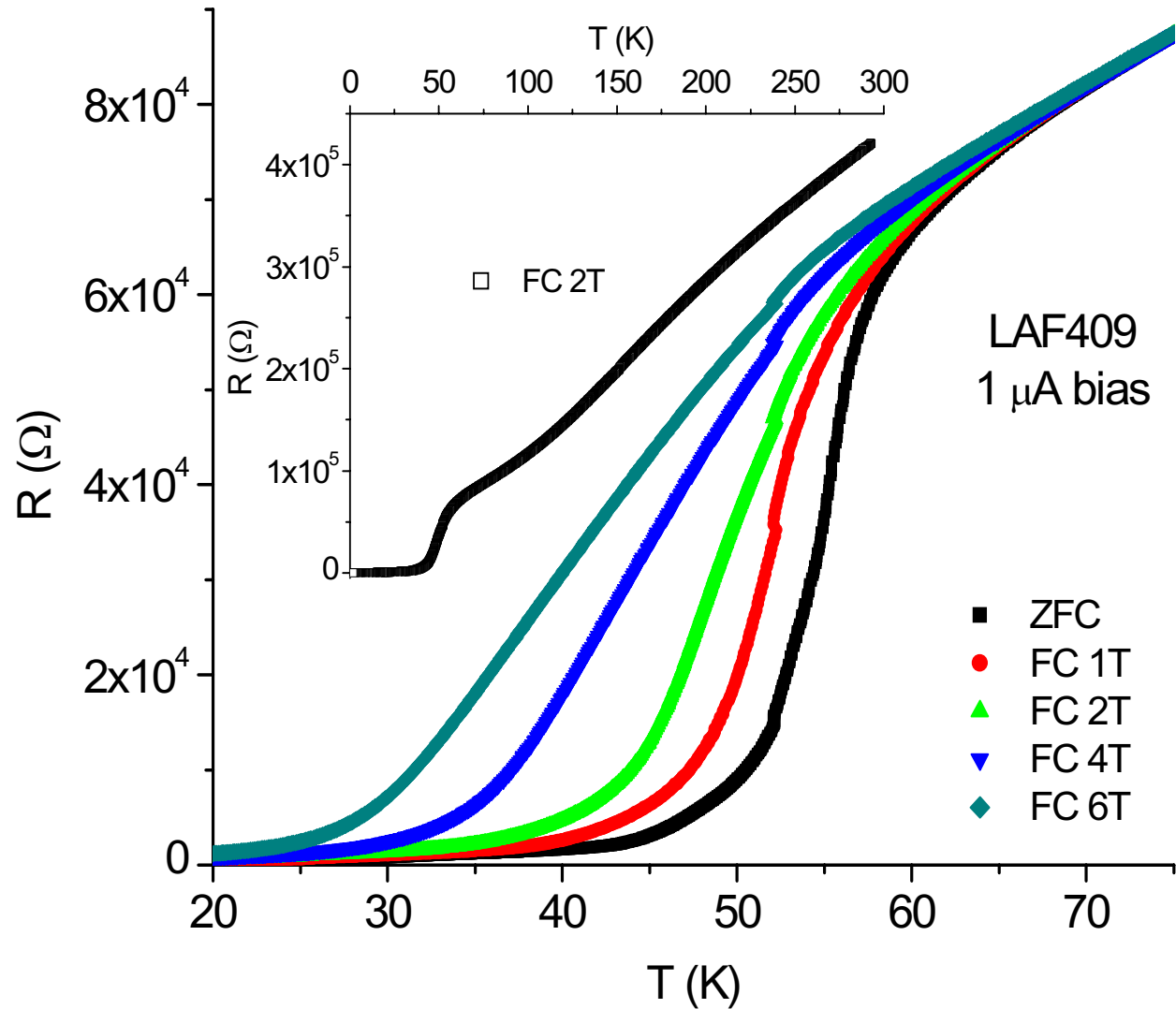


We limited the measurements of  $R_{ff}$   
only to the linear, low-bias, regime where  $V$  is linear in  $I$

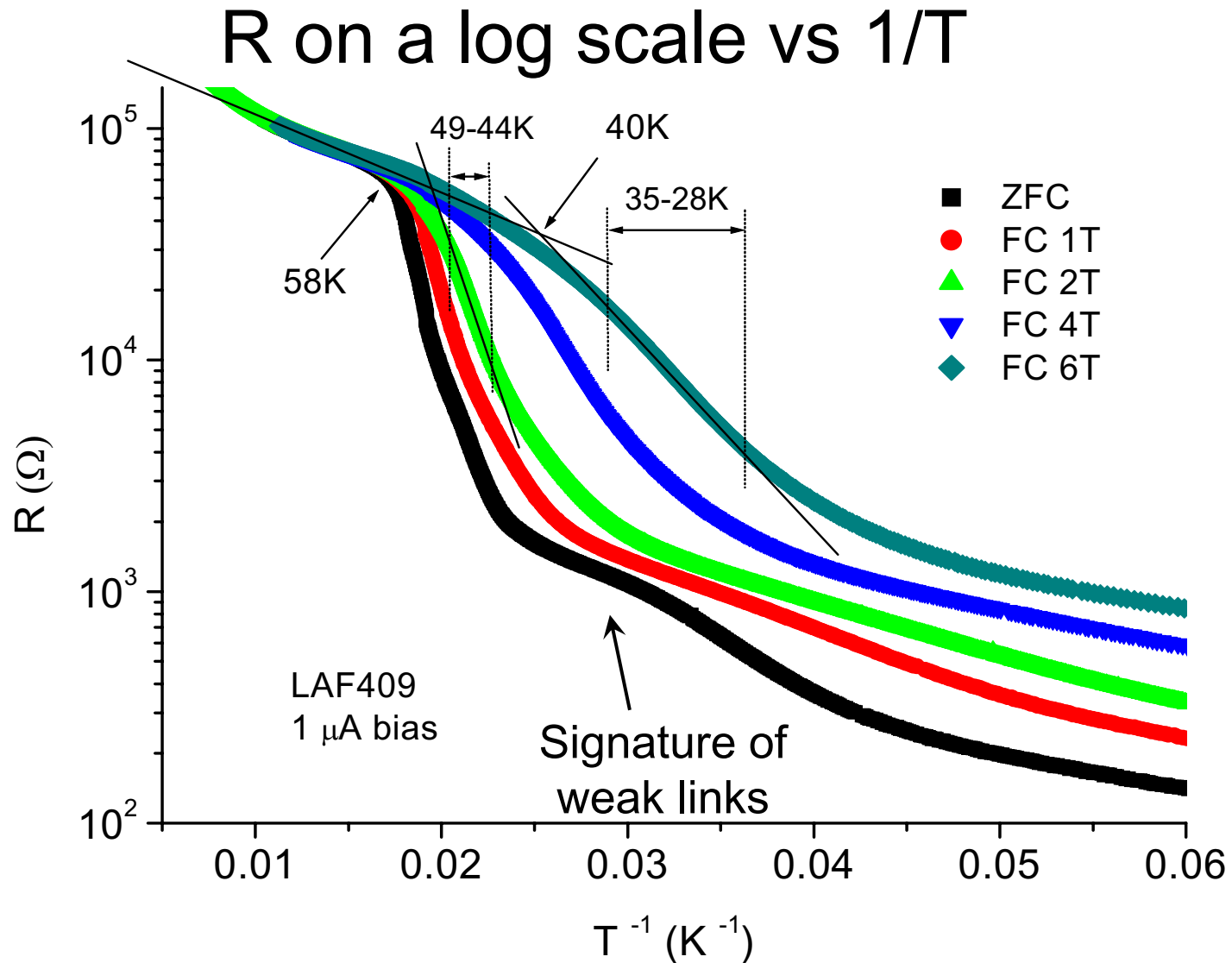
# Transport results of R versus T

Metallic,  
underdoped,  
above  $T_c \sim 60\text{K}$

Typical  
broadening  
with field of  
the transition  
near  $T_c$



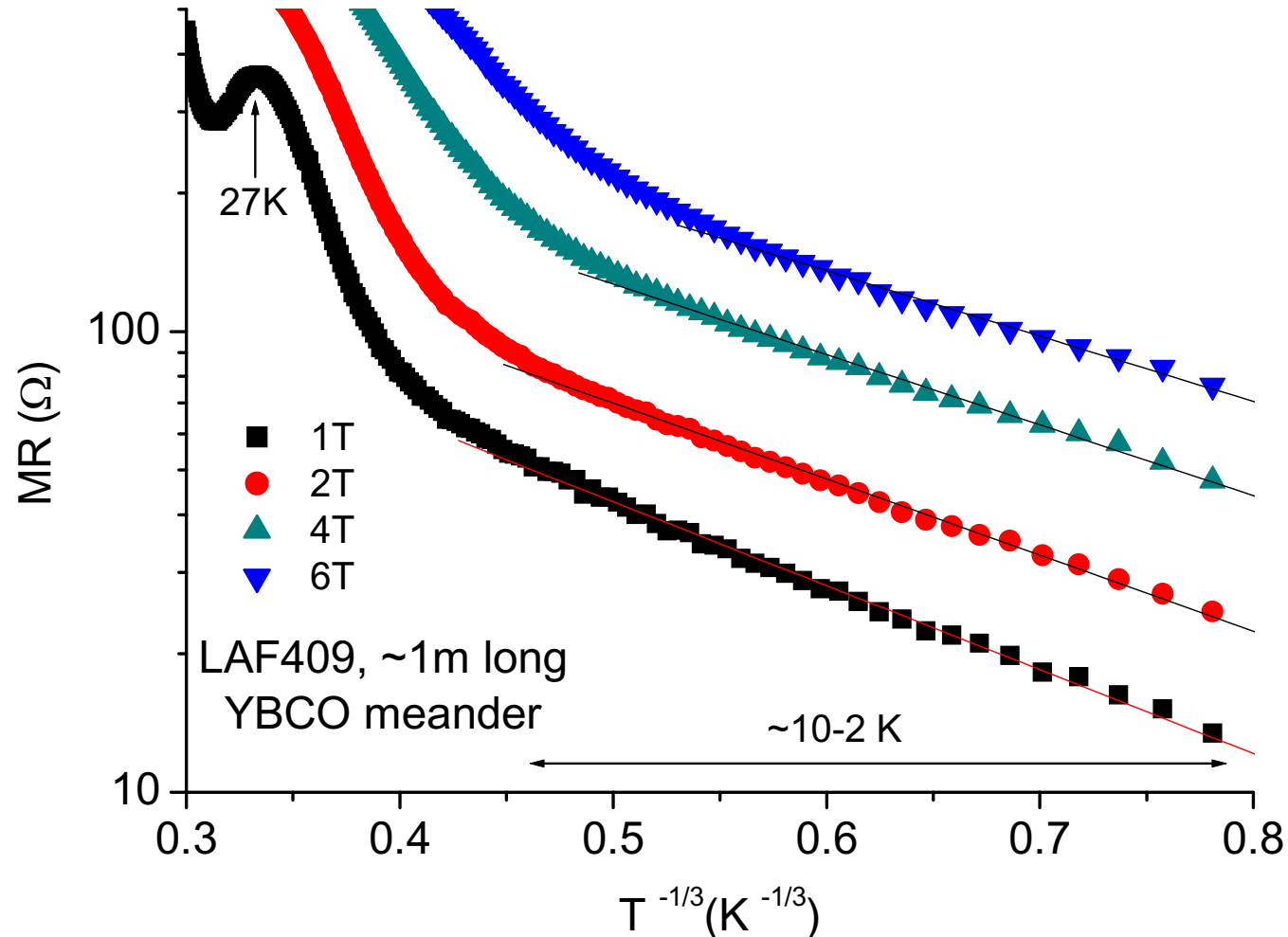




- The activation energy at 2 T can be extracted from  $R_{ff}$ :

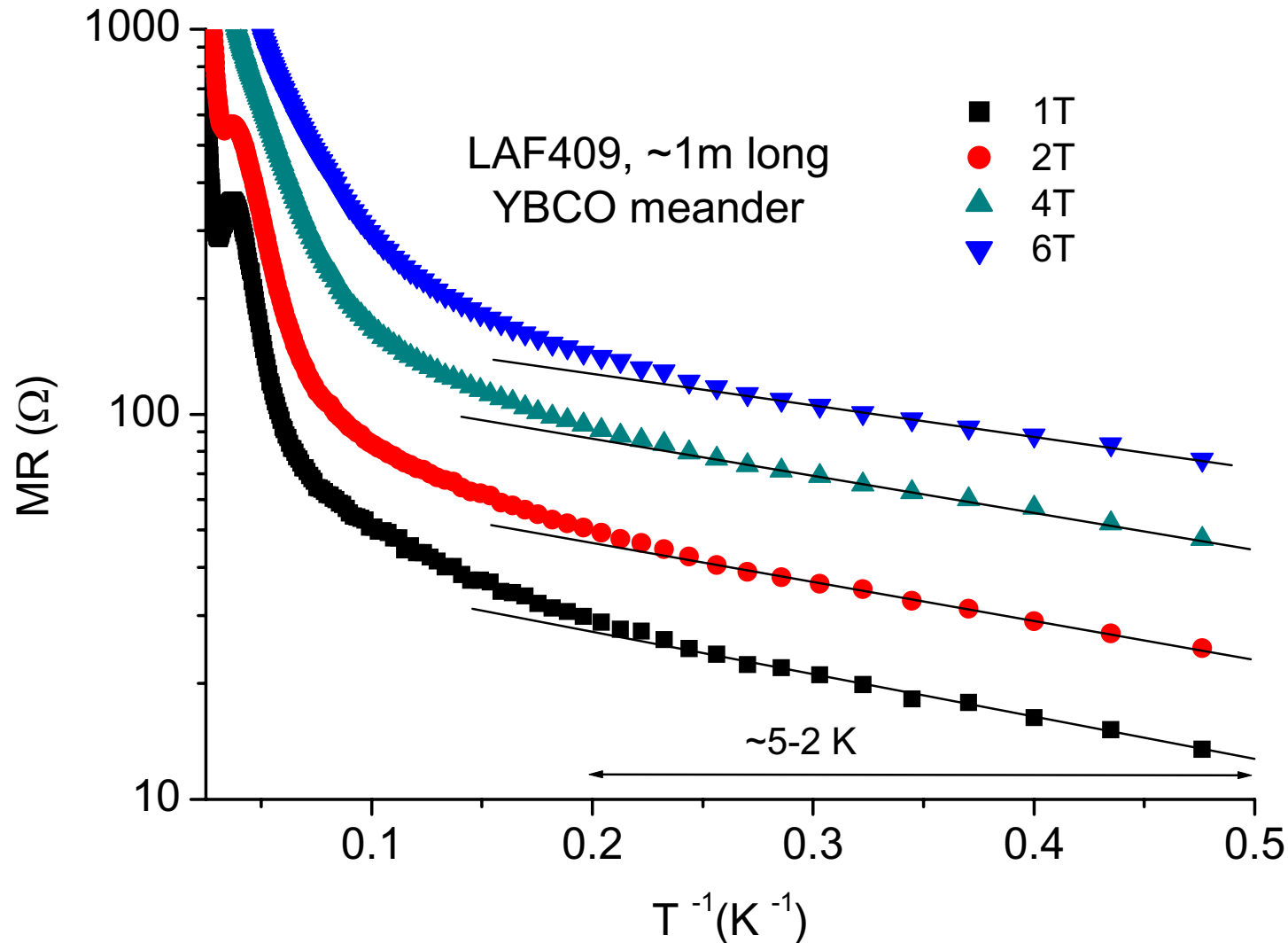
$$R_{ff} \propto \exp\left(-\frac{U_0}{k_B T}\right) \text{ and this yields: } U_0 \sim 550K$$

# To test the Vortex - VRH prediction:



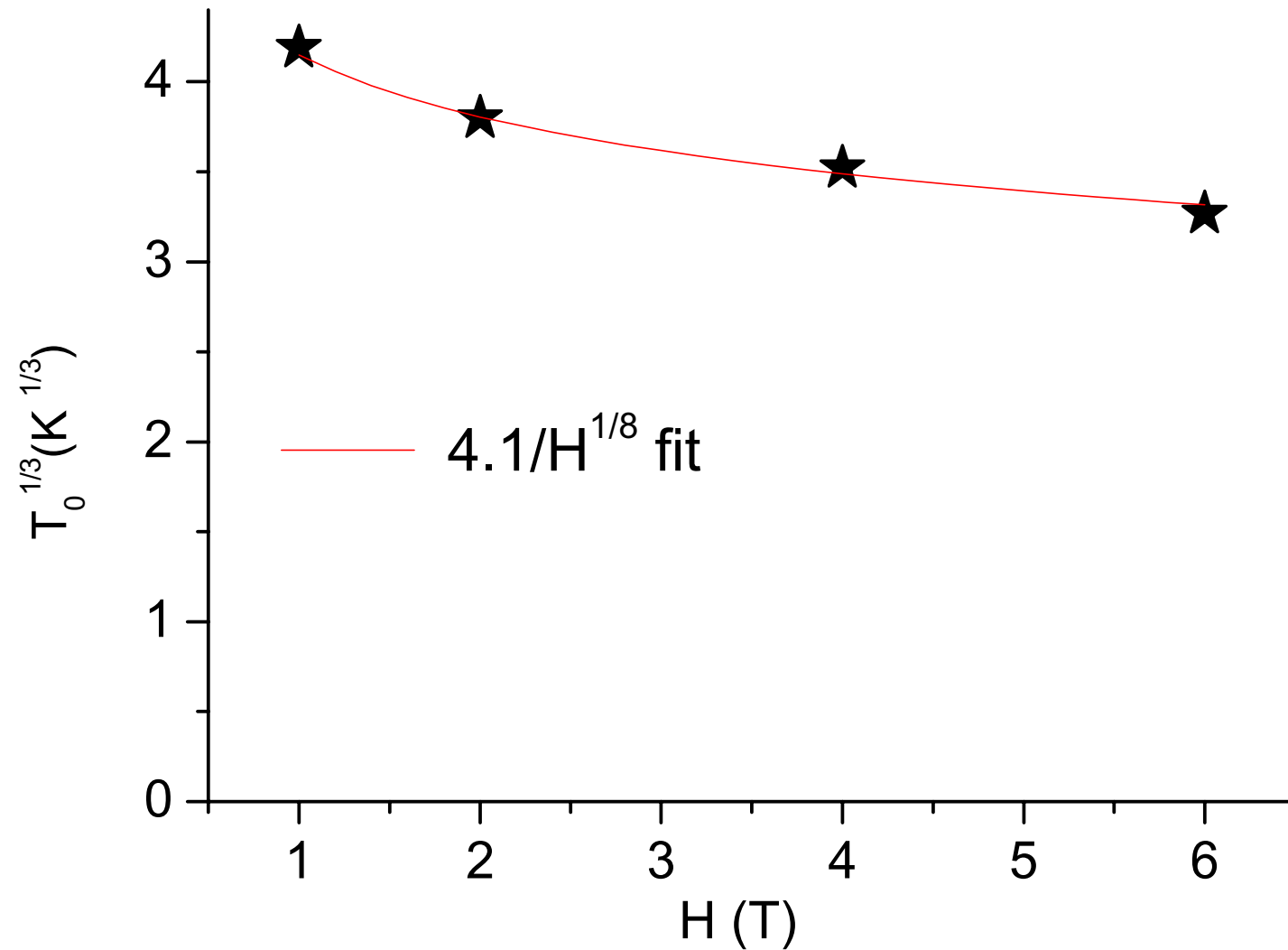
- The linear behavior indicates vortex-VRH in 2D at ~2-10 K
- $T_0$  can be obtained from the slopes of these lines on a **ln** scale

# To test for possible “activation”



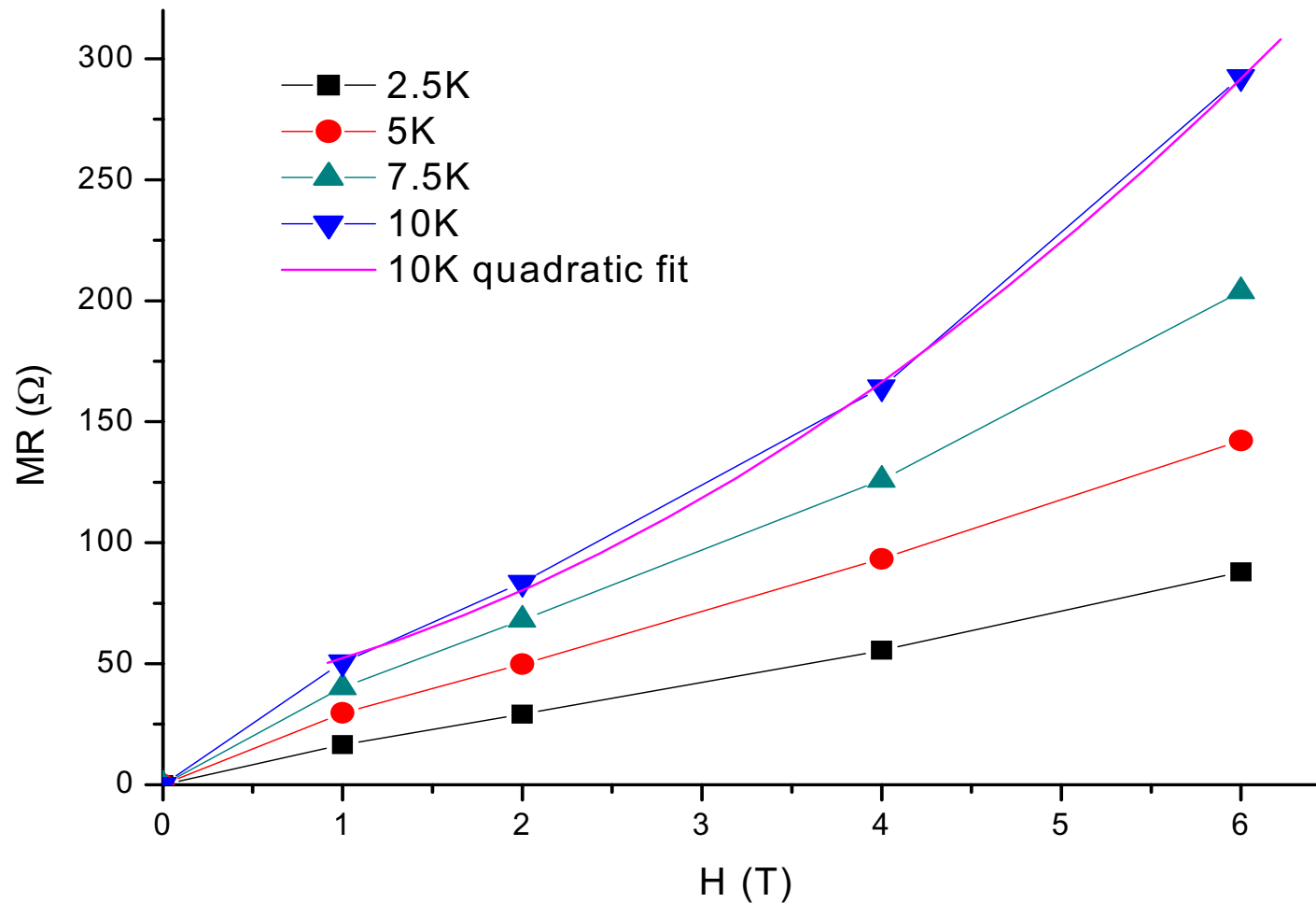
- The larger  $T$  range for observing the  $1/T^{1/3}$  behavior indicates that we actually observe vortex VRH (or vortex tunneling)

# Extraction of $T_0$ from our data



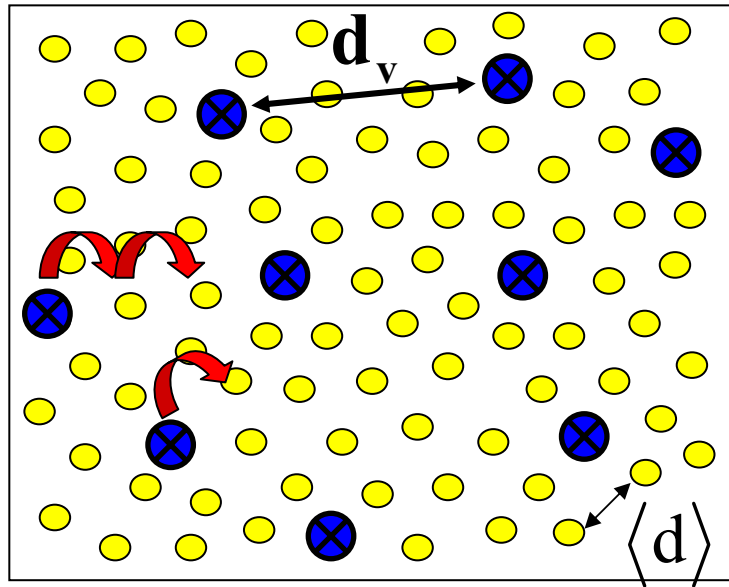
- This  $T_0$  is varying only slowly with  $H$

# Now we check the dependence of MR on H



- At  $T < 5K$ , a constant terminal vortex velocity - yields a linear dependence of the MR vs. H
- At  $T > 7.5 K$ , nonlinearities develop due to the weak-links

# Estimate the pinning sites density from our data



● Pinning site

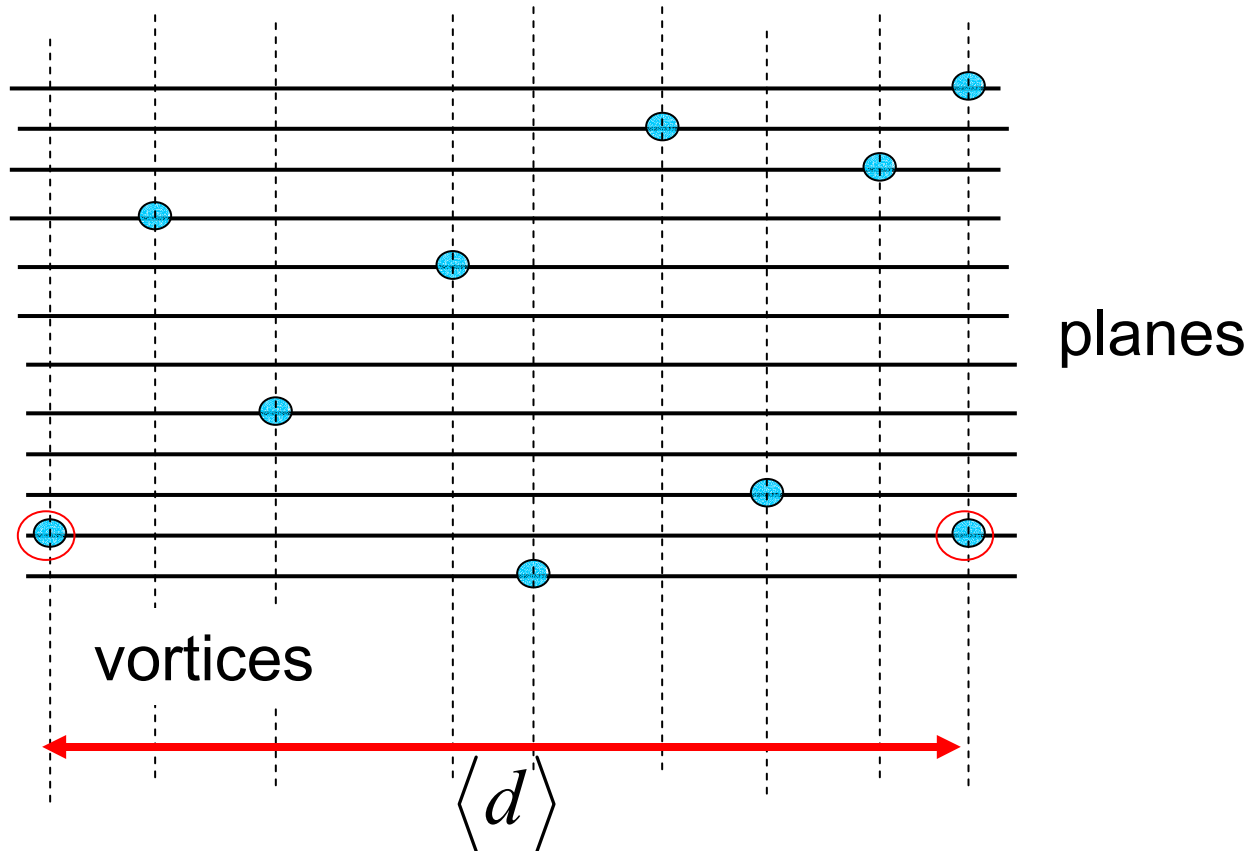
⊗ Vortex

$$T_0 = K \delta \bar{V} \left( \frac{\pi n_s}{n_{pin} N_{layers}} \right)^2$$

- The activation energy at  $H=2$  T just below  $T_c$  is  $U_0 \sim 550$  K.
- For films with  $T_c = 60$  K, the doping per copper in a  $\text{CuO}_2$  plane is  $p = 1/8$  and thus for pairs,  $n_s \sim p/2 = 1/16$ .
- Assuming  $\delta \bar{V} \approx 0.1 U_0$ , and noting that the measured  $T_0 \sim 55$  K, one gets:  $\delta \bar{V} \approx T_0$
- $N_{layers}$  is  $\sim 170$  here, thus the average distance  $\langle d \rangle$  between pinning sites in a  $\text{CuO}$  plane is  $117 \text{ \AA}$ .

And visually it looks like this:

- Pinning sites in different  $\text{CuO}_2$  planes



In a single plane the distance between pinning sites is much larger than  $\xi$

# Conclusions

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- Vortex VRH was observed in YBCO thin films in MR measurements versus temperature
- From our data we extracted the VRH “constant”  $T_0$  which enabled us to estimate the pinning sites density  $n_{\text{pin}}$  & the average distance between pinning sites  $\langle d \rangle$
- $T_0$  was also found to be slightly field dependent
- Further experiments at lower temperatures are needed